



#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
60V	5Ω @ V <sub>GS</sub> = 10V	250mA

## **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine Management Systems
- DC-DC Converters
- Body Control Electronics

#### Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

N-CHANNEL ENHANCEMENT MODE MOSFET

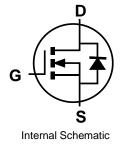
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

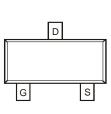
#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)



Top View





Top View

#### Ordering Information (Note 5)

	Part Number	Case	Packaging		
	BS870Q-7-F	SOT23	3000/Tape & Reel		
Notes:	: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.				

No purposery added read. Fully ED Directive 2002/95/EC (NORS), 2017/05/ED (NORS 2) & 2015/063/ED (NORS 3) Compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**

K70	ΥM

 $\begin{array}{l} \mathsf{K70}=\mathsf{Product}\ \mathsf{Type}\ \mathsf{Marking}\ \mathsf{Code}\\ \mathsf{YM}=\mathsf{Date}\ \mathsf{Code}\ \mathsf{Marking}\\ \mathsf{Y}\ \mathsf{or}\ \overline{\mathsf{Y}}=\mathsf{Year}\ (\mathsf{ex:}\ \mathsf{F}=\mathsf{2018})\\ \mathsf{M}=\mathsf{Month}\ (\mathsf{ex:}\ 9=\mathsf{September}) \end{array}$ 

Date Code Key

Eale eeae hey												
Year	2016	2017	2018	2019	2020	2021	202	22 2	023	2024	2025	2026
Code	D	E	F	G	Н		J		К	L	М	Ν
Month	Jar	n Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## Maximum Ratings (@T<sub>A</sub> = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V <sub>DSS</sub>	60	V		
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$	Steady State	T <sub>A</sub> = +25°C	ID	250	mA

#### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 6)		PD	300	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	417	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	С

#### Electrical Characteristics (@T<sub>A</sub> = +25°C unless otherwise specified.)

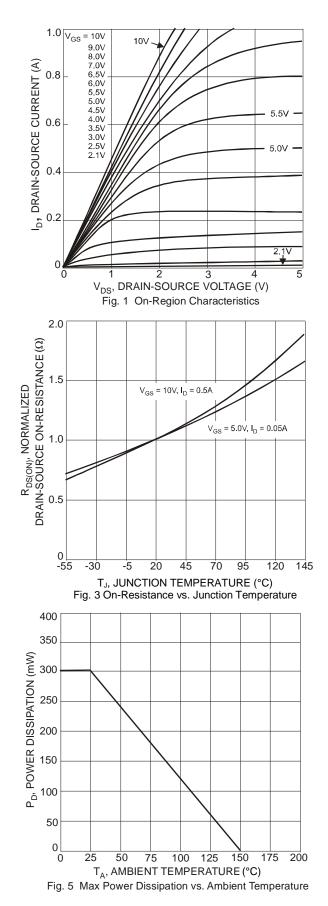
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	<b>BV</b> <sub>DSS</sub>	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	IDSS		_	1	μA	$V_{DS} = 25V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>		_	±100	nA	$V_{GS} = \pm 15V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.0	2.0	3.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	3.5	5.0	Ω	$V_{GS} = 10V, I_D = 0.2A$
DYNAMIC CHARACTERISTICS (Note 8)						÷
Input Capacitance	Ciss		22	50		
Output Capacitance	Coss		11	25	pF	$V_{DS} = 10V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>		2.0	5.0	]	
Turn-On Delay Time	t <sub>D(ON)</sub>		2.0	20	20	$V_{ES} = 10V, R_{L} = 150\Omega,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>		5.0	20	ns	$V_{DS} = 10V, R_{D} = 100\Omega$

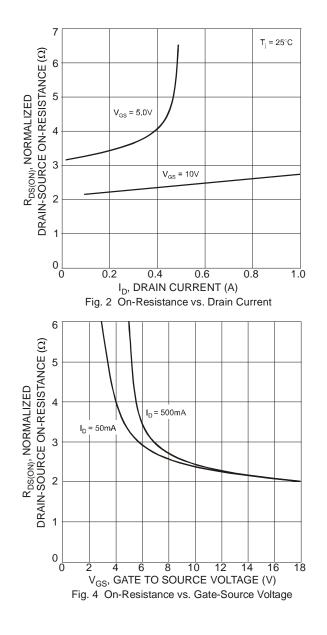
Notes: 6. Device mounted on FR-4 PCB 1.0 x 0.75 x 0.062 inch pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.







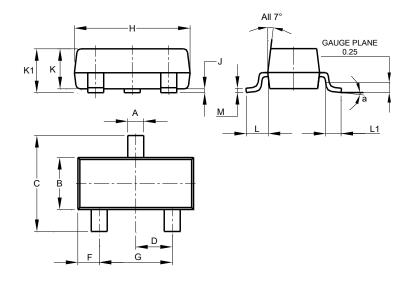


**BS870Q** 

### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

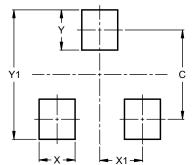


	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	Dimens	ions in	mm					

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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